UNCLASSIFIED

AD 409157

DEFENSE DOCUMENTATION CENTER

FOR

SCIENTIFIC AND TECHNICAL INFORMATION

CAMERON STATION, ALEXANDRIA, VIRGINIA



UNCLASSIFIED

NOTICE: When government or other drawings, specifications or other data are used for any purpose other than in connection with a definitely related government procurement operation, the U. S. Government thereby incurs no responsibility, nor any obligation whatsoever; and the fact that the Government may have formulated, furnished, or in any way supplied the said drawings, specifications, or other data is not to be regarded by implication or otherwise as in any manner licensing the holder or any other person or corporation, or conveying any rights or permission to manufacture, use or sell any patented invention that may in any way be related thereto.



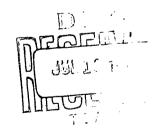
CONTRIBUTION OF THERMAL DIFFUSE SCATTERING TO INTEGRATED BRAGG REFLECTIONS FROM PERFECT CRYSTALS

by

D. R. CHIPMAN

and

B. W. BATTERMAN



MATERIALS RESEARCH LABORATORIES

U. S. ARMY MATERIALS RESEARCH AGENCY
JANUARY 1963

WATERTOWN 72, MASS.

409157

CATALOGED BY DEC. AS AD NO. 4091

The findings in this report are not to be construed as an official Department of the Army position.

ASTIA AVAILABILITY NOTICE

Qualified requesters may obtain copies of this report from Director, Armed Services Technical Information Agency, Arlington Hall Station, Arlington 12, Virginia

DISPOSITION INSTRUCTIONS

Destroy; do not return

CONTRIBUTION OF THERMAL DIFFUSE SCATTERING TO INTEGRATED BRAGG REFLECTIONS FROM PERFECT CRYSTALS

Technical Report AMRA TR 63-03

bу

D. R. Chipman

and

B. W. Batterman

January 1963

MRL Report 130

AMS Code 5026.11.842

D/A Project 1-H-0-24401-A-110

MATERIALS RESEARCH LABORATORIES U.S. ARMY MATERIALS RESEARCH AGENCY WATERTOWN 72, MASS.

U.S. ARMY MATERIALS RESEARCH AGENCY

CONTRIBUTION OF THERMAL DIFFUSE SCATTERING TO INTEGRATED BRAGG REFLECTIONS FROM PERFECT CRYSTALS

ABSTRACT

It is shown that the contribution of thermal diffuse scattering to integrated Bragg intensities from perfect crystals can be much greater than previously expected. Measurements on the (555) reflection of silicon are presented showing a thermal scattering contribution of about 70% of the true Bragg intensity. The special aspect of the effect in perfect crystals is discussed and methods of reducing it or correcting for it are included.

D. R. CHIPMAN (

Physicist

U.S. Army Materials Research Agency

B. W. BATTERMAN

Physicist

Bell Telephone Laboratories

APPROVED:

HOMER F. PRIEST

Acting Director

Materials Research Laboratories

Signatures of any nonmembers of the organization issuing this report attest not only substantial technical responsibility for contents but compliance with publication policies of their firms or organizations.

INTRODUCTION

Thermal diffuse scattering (TDS) of X-rays or neutrons generally makes up an important part of what is called the "background" in a diffraction pattern. This diffuse scattering is not independent of angle, but has peaks at the same places where Bragg reflections occur. As shown by Nilsson¹ and by Chipman and Paskin² these peaks will lead to errors in measured integrated Bragg intensities if a straight line background under the reflection is erroneously assumed. For example, an error of 15% for the (511) reflection of lead powder has been reported.²

It is the purpose of this note to point out that for crystals of high perfection, this effect can be many times larger. Starting from an imperfect crystal, as the perfection is increased, extinction increases, and Bragg intensities decrease. However, the TDS intensity function is very weak, so that it is scarcely affected by extinction and its value, even in a perfect crystal, is given by a mosaic crystal formula. Therefore, as perfection is increased, the TDS peak becomes a relatively larger fraction of the Bragg peak, resulting in an enhancement of the effect. This enhancement can become as large as the ratio of integrated intensities calculated from the mosaic and perfect crystal formulas.³

In practice, the occurrence or at least the observation of this effect depends markedly on the experimental geometry. The TDS peaks are very broad functions on an angular scale, and the TDS contribution to a Bragg peak varies almost linearly² with the total range of integration, i.e., the total length of the background line drawn under the peak. Therefore, if a perfect crystal is measured in a double crystal spectrometer in the parallel position, the TDS contribution will seem to be very small since the total width of the scan is typically only a few tens of seconds of arc. Of course if the scan were actually carried out over a range of several degrees, the TDS peak would be observed and the effect discussed above would be obtained. However, with such a narrow peak there is little temptation to do so.

In contrast to the above case, Fig. 1 shows the (555) reflection of perfect crystal silicon obtained by rocking the crystal through the entire reflecting range in a monochromatic primary beam of about one degree divergence. Here the Bragg reflection is spread out instrumentally over about two degrees in 2θ , and the TDS becomes quite apparent. It will be shown below that the true Bragg peak is approximately that area above the dotted line, the rest being contributed by TDS.

The intensity scale of Fig. 1 was determined in absolute units by a direct measurement of the primary beam using absorbers. Several methods are therefore available by which we can determine the relative amounts of TDS and Bragg reflection in Fig. 1. First, we calculated the TDS in the vicinity of the reflection by making use of the measured value of the Debye-Waller factor of silicon. A brief discussion of the calculation and the assumptions made is given in the Appendix. The results of the calculation are shown as the solid points in Fig. 1.

Second we have compared the measured integrated intensity of the reflection in Fig. 1, with an experimental value which we have measured using a double crystal spectrometer, and with the theoretical (Darwin-Prins) value. The comparison is made by measuring the area above a straight line which is allowed to range between the solid and the dotted lines of Fig. 1, while remaining parallel to both. This area is plotted against the length of the corresponding background line, as shown in Fig. 2. This figure shows that as the range of integration is narrowed, the intensity approaches the experimental double crystal or theoretical values.

Third, we have used a theoretical expression which gives the ratio of the TDS area to the Bragg peak area for a powder sample.² This expression should not, of course, be expected to give the exact correction for a single crystal, but it is probably not greatly in error. Since the expression is derived for the TDS correction to ideally imperfect crystal Bragg peaks,

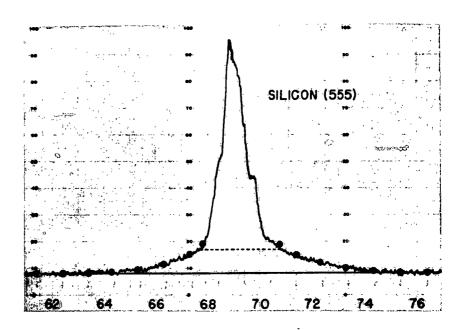
we increase it by the ratio of the intensities calculated from the mosaic and perfect crystal formulas so that it will apply to a perfect crystal. This factor for the (555) reflection of silicon and MoKa radiation is about 7. This expression gives the fraction of the area which is TDS as a function of the width of integration. In Fig. 2, we have drawn it to intercept the intensity axis at the double crystal spectrometer value, from which it matches the initial data points quite well.

These three different approaches all lead to the same conclusion, that the area above the straight line background in Fig. 1 is some 70% too large, and that this extra scattering is a result of TDS. This enhancement, which occured because the crystal was perfect, has thus changed what might have been thought of as an almost negligible correction into a very important one. For the (111) reflection, the factor is about 27, which increases a mosaic crystal TDS correction of 0.15% for our geometry up to about 4%, a value which we have also verified experimentally.

In conclusion, under certain conditions which are not particularly unusual, the TDS correction can be very large. The geometry of the diffraction experiment is quite important in determining how large the contribution of TDS will be, and by giving some thought to this, the contribution may be substantially reduced for a given measurement. In any case, the correction will always become larger when the divergences in the X-ray system are increased or when the perfection of the sample becomes greater.

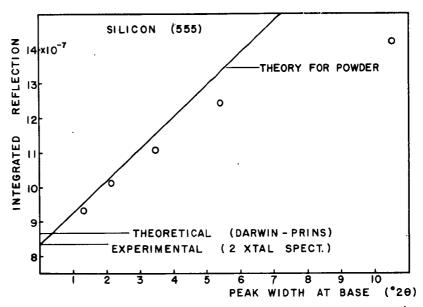
APPENDIX

In the vicinity of a Bragg reflection, the optic mode scattering is negligible compared with the acoustic mode. Hence only the intensity resulting from the acoustic mode was calculated, by assuming that all elastic waves have the same velocity, and obtaining this velocity from the experimental value of the Debye-Waller factor (Batterman & Chipman, 1962). A curve of TDS intensity versus angle was calculated from this intensity function for the particular geometrical arrangement of the apparatus using a numerical method of averaging over the receiving volume element. All other sources of background scattering near the peak (Compton scattering, etc.) were assumed to be independent of angle, so a constant was added to the calculated TDS to make it match the curve of Fig. 1 at some one angle. Both the TDS and the intensity scale of Fig. 1 had to be known in the same intensity units to make this possible. This was done by measuring the total power in the direct beam using absorbers. 5



19-066-1805/ORD-61

Figure 1. The (555) reflection of a silicon single crystal measured using a monochromatic primary beam having a divergence of about one degree. The crystal was rocked through the entire reflecting range with a wide open counter. Intensity is plotted versus 2θ . Filled circles are the calculated thermal diffuse scattering.



19-066-1804/ORD-61

Figure 2. The integrated intensity from Figure 1 measured above a horizontal line lying between the solid and dotted lines of Figure 1, versus the length of the horizontal line (open circles). Also shown are the theoretical and experimental values for the integrated intensity of the (555) reflection of silicon, and the Chipman & Paskin² powder theory.

REFERENCES

- 1. N. Nilsson, Arkiv Fysik 12, 247 (1957).
- 2. D. R. Chipman and A. Paskin, J. Appl. Phys. 30, 1998 (1959).
- 3. R. W. James, "The Optical Principles of the Diffraction of X-rays" (G. Bell & Sons, Ltd., London, 1948), p. 269.
- 4. B. W. Batterman and D. R. Chipman, Phys. Rev. 127, 690 (1962).
- 5. B. W. Batterman, D. R. Chipman, and J. J. DeMarco, Phys. Rev. <u>122</u>, 68 (1961).

Materials Research Laboratories U.S. Army Materials Research Agency Watertown 72, Mass.

TECHNICAL REPORT DISTRIBUTION

Report No. AMRA TR 63-03 January 1963

Title: Contribution of Thermal Diffuse Scattering to Integrated Bragg Reflections from Perfect Crystals

No. of Copies	то												
1	Advanced Research Projects Agency, The Pentagon, Washington 25, D.C.												
10	Armed Services Technical Information Agency, Arlington Hall Station Arlington 12, Virginia												
1	Defense Metals Information Center, Battelle Memorial Institute, Columbus 1, Ohio												
1	Commanding Officer, U.S. Army Research Office, Arlington Hall Station, Arlington 12, Virginia												
1	Commanding Officer, Army Research Office (Durham), Box CM, Duke Station, Durham, North Carolina ATTN: Physics Division												
1 1 1 1	Commanding General, U. S. Army Materiel Command, Washington 25, D.C. ATTN: AMCRD-RS, Research Division AMCRD-RS, Scientific Deputy AMCRD-RS-CM, Mr. J. Kaufman AMCRD-RS-CM-M, Dr. P. Kosting AMCRD-DE, Development Division												
1	Commanding General, U.S. Army Electronics Command, Fort Monmouth, New Jersey ATTN: Institute for Fundamental Research												
1 1 1	Commanding General, U. S. Army Missile Command, Redstone Arsenal, Huntsville, Alabama ATTN: AMSMI-RB, Redstone Scientific Information Center Directorate of R&D Chief Scientist, Dr. W. W. Carter Dr. B. Steverding												
1	Commanding General, U. S. Army Mobility Command, 28251 Van Dyke Avenue, Center Line, Michigan ATTN: Physical Sciences Laboratory												
1	Commanding General, U. S. Army Munitions Command, Dover, New Jersey ATTN: Chief Scientist												

Commanding Officer, Watervliet Arsenal, Watervliet, New York

1 ATTN: Research Branch

Commander, Office of Naval Research, Department of the Navy, Washington 25, D. C.

61 -- TOTAL COPIES DISTRIBUTED

	UNCLASSIFIED 1. 1-ray scattering	2. Phonons	I. Chipman, D. R.	II. Batterman, B.W.	<pre>III. AMS Code 5026.11.842</pre>	IV. D/A Project 1-H-0-24401- A-110		UNCLASSIFIED	1. X-ray scattering	2. Phonons	I. Chipman, D.R.	II. Batterman, B.W.	III. AMS Code 5026.11.842	IV. D/A Project 1-H-0-24401- A-110	
	AD U.S. Anny Materials Research Agency, Watertown 72, Mass. CONTRIBUTION OF THERMAL DIPPUSE SCATTERING TO INTEGRATED BRAGG REPLECTIONS FROM PERFECT CRISIALS - D.R. Chipman	AMRA TR 63-03, January 1963, 8 pp, illus - appendir, AMS Code 5026, 11-842, D/A Project 1-H-0-24401-A-110, Unclassified Report	It is shown that the contribution of thermal diffuse scattering to integrated Bragg intensities from perfect crystals can be much preater than previously expected. Measurements on the (555) reflection of shiron are	presented showing a thermal scattering contribution of about 70% of the true Bragg intensity. The special aspect of the effect in perfect crystals is discussed	and methods of reducing it or correcting for it are included.	NO DISTRIBUTION LIMITATIONS		AD Army Materials Research Agency, Watertown 72, Mass.	CONTRIBUTION OF THERMAL DIFFUSE SCATTERING TO INTEGRATED BRACG REFECTIONS FROM PERPECT CRISIALS - D.R. Chipman and B.W. Batterman	AMS Code 5026.11.842, D/A Project 1-H-0-24401-A-110, Unclassified Report	It is shown that the contribution of thermal diffuse scattering to integrated Bragg intensities from perfect Cygystals can be much greater in han previously expected. Measurements on the first actions in the first actions in the first actions and the first actions are actions and the first actions actions and the first actions actions and the first actions actions actions and the first actions actions and the first actions actions actions and the first actions actions actions and the first actions act	presented showing a thermal scattering contribution of assert 10% of the free Bragg intensity. The agectal assert the transfer in references.	and methods of reducing it or correcting for it are included.	NO DISTRIBUTION LIMITATIONS	
) 1	UNCLASSIFIED I. X-ray scattering	2. Phonons			<pre>III. AMS Code 5026.11.842</pre>	IV. D/A Project 1-H-0-24401- A-110		UNCLASSIFIED	L X-ray scattering	2. Phonons	I. Chipman, D. R.	II. Batterman, B.W.	III. AMS Code 5026.11.842	IV. D/A Project 1-H-0-24401- A-110	
	AD. J. S. Army Materials Research Agency, Watertown 72, Mass. CONTRIBUTION OF THERMAL DIFFUSE SCATTERING TO INTEGRATED BRAGG REFLECTIONS FROM PERFECT CRYSTALS - D.R. Chipman and B.W. Batterman		It is shown that the contribution of thermal diffuse scattering to integrated Bragg intensities from Perfect crystals can be much greater than previously expected. Measurements on the (555) reflection of silicon are	Presence showing a thermal scattering contribution of about 70% of the true Bragg intensity. The special aspect of the effect in perfect crystals is discussed	and methods of reducing it or correcting for it are included.	NO DISTRIBUTION LIMITATIONS	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	J. S. Army Materials Research Agency, Watertown 72, Mass. CONTRERRITION OF THERMAI DIEBRIS COARMEDING TO THE PARTY OF THE	BOARD TO THE STATE OF THE STATE	AMRA TR 63-03, January 1963, 8 pp, illus - appendix, AMS Code 5026.11.842, D/A Project 1-H-0-24401-A-110, Unclassified Report	It is shown that the contribution of thermal diffuse scattering to integrated Bragg intensities from perfect crystals can be much greater than previously expected. Measurements on the (555) reflection of silicon are	presented showing a thermal scattering contribution of about 70% of the true Bragg intensity. The special aspect of the effect in perfect crystals is discussed	and methods of reducing it or correcting for it are included.	NO DISTRIBUTION LIMITATIONS	